

SANYO	No. 1207A	2SC3277
NPN Triple Diffused Planar Silicon Transistor FOR SWITCHING REGULATORS		

Features

- . High breakdown voltage, high current.
- . Wide ASO.
- . Fast switching speed.

Absolute Maximum Ratings at Ta=25°C

			unit
Collector-to-Base Voltage	V _{CBO}	500	V
Collector-to-Emitter Voltage	V _{CEO}	400	V
Emitter-to-Base Voltage	V _{EBO}	7	V
Collector Current	I _C	10	A
Peak Collector	i _{cp}	20	A
		PW ≤ 300μs, Duty Cycle ≤ 10%	
Collector Dissipation	P _C	90	W
		T _c = 25°C	
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Electrical Characteristics at Ta=25°C

			min	typ	max	unit
Collector Cutoff Current	I _{CBO}	V _{CB} = 400V, I _E = 0			10	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} = 5V, I _C = 0			10	μA
DC Current Gain	h _{FE} (1)	V _{CE} = 5V, I _C = 1.2A	15*		50*	
	h _{FE} (2)	V _{CE} = 5V, I _C = 6A	8			
Gain-Bandwidth Product	f _T	V _{CE} = 10V, I _C = 1.2A		20		MHz
Output Capacitance	c _{ob}	V _{CB} = 10V, f = 1MHz		120		pF
C-E Saturation Voltage	V _{CE(sat)}	I _C = 6A, I _B = 1.2A			1.0	V
B-E Saturation Voltage	V _{BE(sat)}	I _C = 6A, I _B = 1.2A			1.5	V
C-B Breakdown Voltage	V _{(BR)CBO}	I _C = 1mA, I _E = 0	500			V
C-E Breakdown Voltage	V _{(BR)CEO}	I _C = 5mA, R _{BE} = ∞	400			V
E-B Breakdown Voltage	V _{(BR)EBO}	I _E = 1mA, I _C = 0	7			V
C-E Sustain Voltage	V _{CEO(sus)}	I _C = 10A, I _B = 2A, L = 50μH	400			V

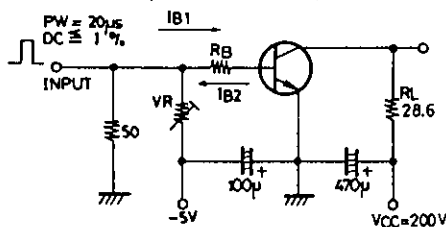
Continued on next page.

*: The h_{FE}(1) of the 2SC3277 is classified as follows. When specifying the h_{FE}(1) rank, specify two ranks or more in principle.

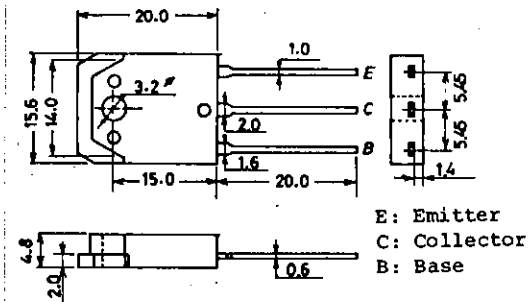
15	L	30	20	M	40	30	N	50
----	---	----	----	---	----	----	---	----

Package Dimensions 2022
(unit: mm)

Switching Time Test Circuit



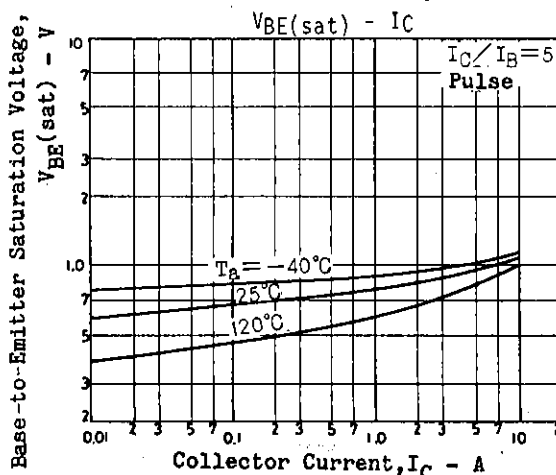
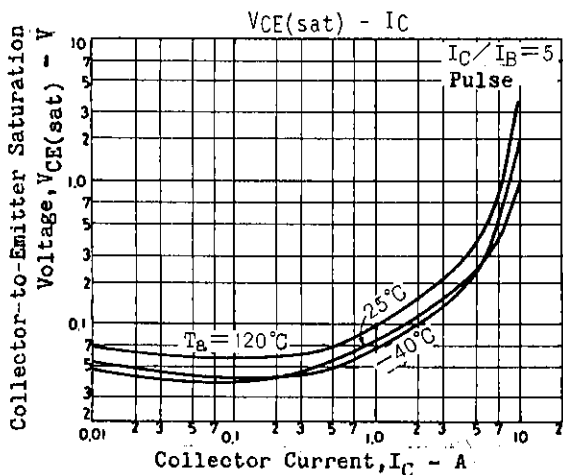
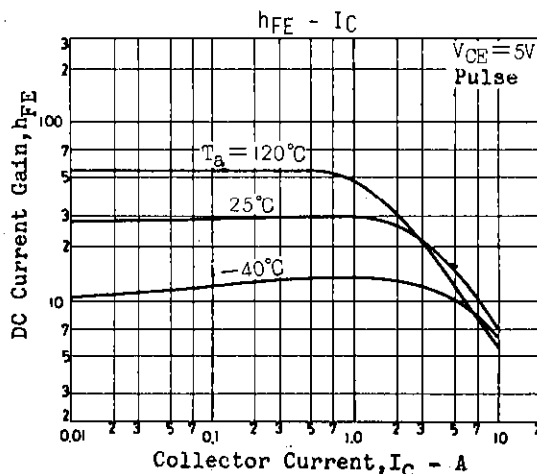
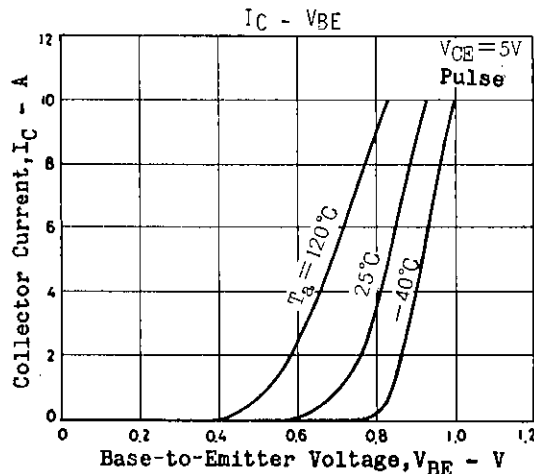
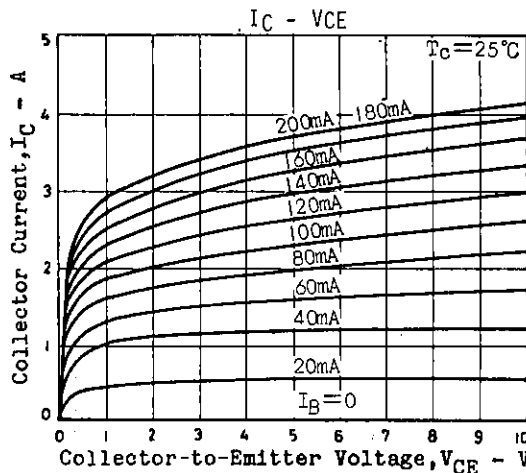
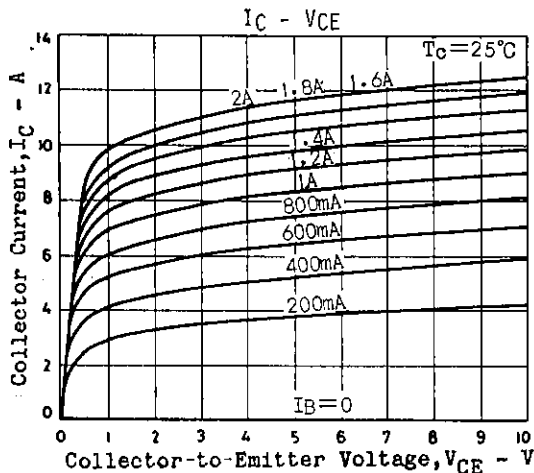
Unit (Resistance : Ω, Capacitance : F)

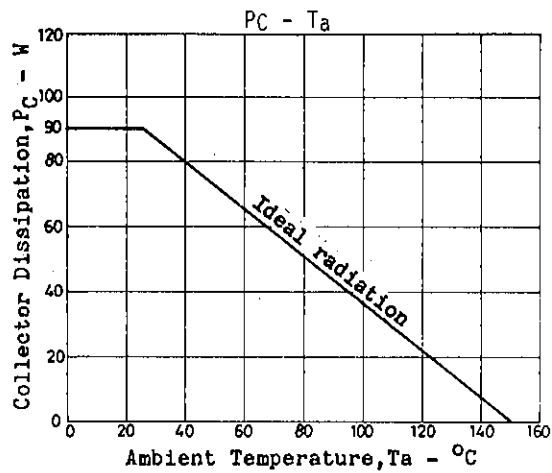
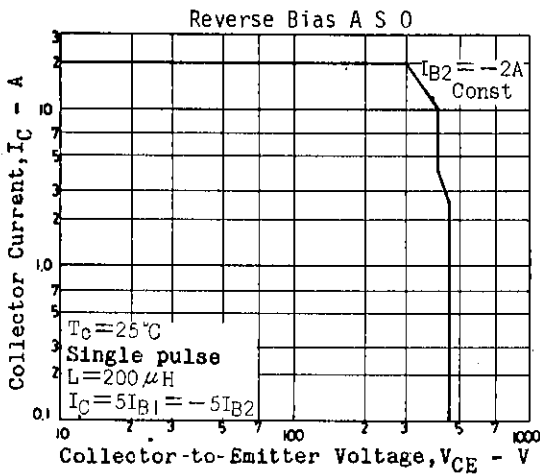
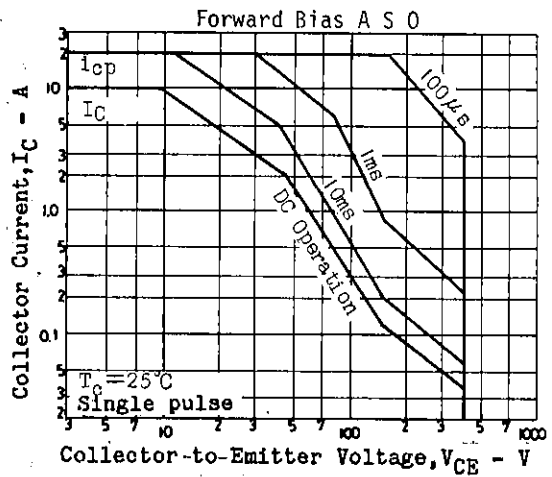
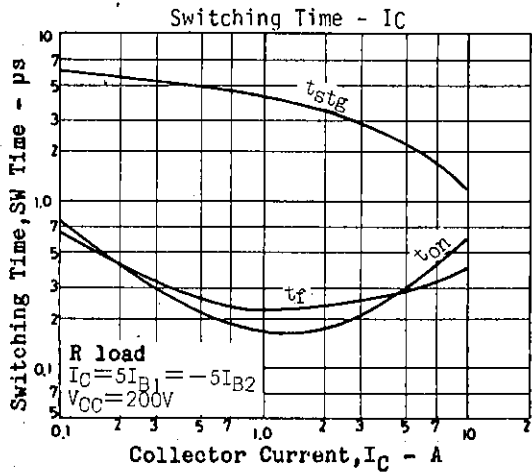


E: Emitter
C: Collector
B: Base

Continued from preceding page.

			min	typ	max	unit
C-E Sustain Voltage	$V_{CEX(sus)}$ (1)	$I_C=10A, I_{B1}=2A, L=200\mu H,$ $I_{B2}=-2A, \text{clamped}$	400			V
C-E Sustain Voltage	$V_{CEX(sus)}$ (2)	$I_C=2.5A, I_{B1}=0.5A, L=200\mu H,$ $I_{B2}=-0.5A, \text{clamped}$	450			V
Turn-ON Time	t_{on}	$I_C=7A, I_{B1}=1.4A, I_{B2}=-1.4A,$ $R_L=28.6\text{ohms}, V_{CC}=200V$			1.0	μs
Storage Time	t_{stg}	" "			2.5	μs
Fall Time	t_f	" "			1.0	μs





■ No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.

■ Anyone purchasing any products described or contained herein for an above-mentioned use shall:

- ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use;
- ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.

■ Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.